Vishay Semiconductors



SOT-227 Power Module Insulated Standard Recovery Rectifier, 160 A



SOT-227

#### FEATURES

- Two fully independent diodes
- Fully insulated package



COMPLIANT

- High voltage rectifiers optimized for very low forward voltage drop
- Industry standard outline
- UL approved file E78996
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

#### **DESCRIPTION / APPLICATIONS**

These devices are intended for use in main rectification. Single or three phase bridge.

PRIMARY CHARACTERISTICS						
I <sub>F(AV)</sub> per module	160 A, T <sub>C</sub> = 101 °C					
V <sub>FM</sub> typical at 100 A	1.16 V					
Туре	Modules - diode, high voltage					
Package	SOT-227					
Circuit configuration	Two separate diodes, parallel pin-out					

MAJOR RATINGS AND CHARACTERISTICS							
SYMBOL	CHARACTERISTICS	VALUES	UNITS				
I <sub>F(AV)</sub>	90 °C	91					
I <sub>F(RMS)</sub>		138	A				
1	50 Hz	940					
IFSM	60 Hz	985					
l <sup>2</sup> t	50 Hz	4420	— A <sup>2</sup> s				
1-1	60 Hz	4015	A-S				
l²√t		44 180	A²√s				
V <sub>RRM</sub>		1200	V				
TJ		-55 to +150	°C				
T <sub>Stg</sub>		-40 to +150	°C				

#### **ELECTRICAL SPECIFICATIONS**

VOLTAGE RATINGS									
TYPE NUMBER	VOLTAGE CODE	V <sub>RRM,</sub> MAXIMUM REPETITIVE PEAK REVERSE VOLTAGE V	V <sub>RSM</sub> , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I <sub>RRM</sub> TYPICAL AT 150 °C mA					
VS-RA160FA120	120	1200	1300	1.0					

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FORWARD CONDUCTION						
PARAMETER	SYMBOL		TEST CON	VALUES	UNITS	
Maximum average forward current at case temperature per leg	I <sub>F(AV)</sub>	180° condu	180° conduction, half sine wave, 90 °C			А
Maximum RMS forward current per leg	I <sub>F(RMS)</sub>	DC at 101 °	°C case temper	ature	138	
		t = 10 ms	No voltage		940	
Maximum peak, one-cycle forward,		t = 8.3 ms	reapplied		985	А
non-repetitive surge current per leg	I <sub>FSM</sub>	t = 10 ms	100 % V <sub>RRM</sub>	Sinusoidal half wave, initial $T_J = T_J maximum$	790	
		t = 8.3 ms	reapplied		825	
		t = 10 ms	No voltage		4420	A <sup>2</sup> s
Maximum I <sup>2</sup> t for fusing per leg	l <sup>2</sup> t	t = 8.3 ms	reapplied		4015	
Maximum 1-t for fusing per leg		t = 10 ms	100 % V <sub>RRM</sub>		3125	
		t = 8.3 ms	reapplied		2840	
Maximum I²√t for fusing per leg	l²√t	t = 0.1 ms t	o 10 ms, no vo	Itage reapplied	44 180	A²√s
Low level of threshold voltage per leg	V <sub>F(TO)1</sub>	(16 7 0/ x -			0.80	V
Low level value of forward slope resistance	r <sub>f1</sub>	$(16.7 \% x \pi x I_{F(AV)}) < I < \pi x I_{F(AV)}, T_J = T_J \text{ maximum}$			4.32	mΩ
High level of threshold voltage per leg	V <sub>F(TO)2</sub>	$(I > \pi \times I_{F(AV)}), T_J = T_J maximum$			0.93	V
High level value of forward slope resistance	r <sub>f2</sub>	$(I > \pi \times I_{F(AV)})$	y, $y = y$ maximaxing	4.14	mΩ	
Maximum famuard valtage dwap per lag	V	I <sub>FM</sub> = 100 A	, T <sub>J</sub> = 25 °C	1.27	V	
Maximum forward voltage drop per leg	V <sub>FM</sub>	I <sub>FM</sub> = 100 A	, T <sub>J</sub> = 150 °C		1.22	V

BLOCKING								
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS				
Maximum peak reverse leakage current	1	T <sub>J</sub> = 25 °C	150	μA				
per leg	IRRM	T <sub>J</sub> = 150 °C	1.5	mA				
RMS insulation voltage	V <sub>INS</sub>	$T_J = 25 \text{ °C}$ , any terminal to case, t = 1 minute	2500	V				

THERMAL AND MECHANICAL SPECIFICATIONS									
PARAMETER	SYMBOL	MIN.	TYP.	MAX.	UNITS				
Thermal resistance,	per leg	Р	-	-	0.26				
junction to case	per module	R <sub>thJC</sub>	-	-	0.13	°C/W			
Thermal resistance, case to heatsink	per module	R <sub>thCS</sub>	-	0.1	-				
Weight			-	30	-	g			
Mounting torque to terminal			-	-	1.1 (9.7)	Nm (lbf. in)			
Mounting torque to heatsink			-	-	1.8 (15.9)	Nm (lbf. in)			
Case style			SOT-227						

DEVICE	S	INE HALF	WAVE CO	NDUCTIO	N	REC	CTANGULA	AR WAVE (	CONDUCT	ION	UNITS
DEVICE	180°	120°	90°	60°	30°	180°	120°	90°	60°	30°	°C/W
VS-RA160FA120	0.109	0.122	0.149	0.213	0.355	0.069	0.119	0.159	0.223	0.358	0/10

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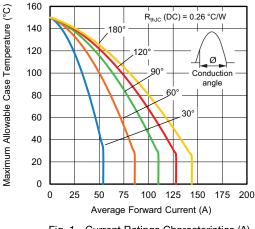


Fig. 1 - Current Ratings Characteristics (A)

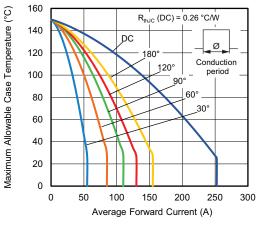


Fig. 2 - Current Ratings Characteristics (A)

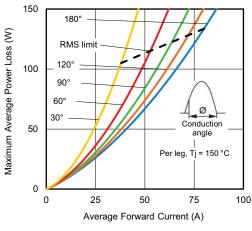


Fig. 3 - Current Ratings Characteristics (A)

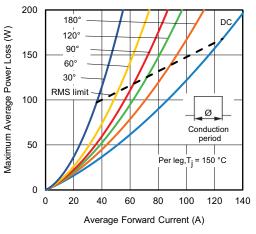


Fig. 4 - Forward Power Loss Characteristics

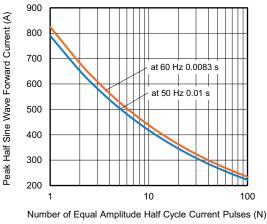


Fig. 5 - Forward Power Loss Characteristics

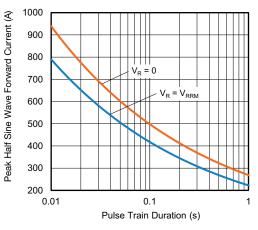


Fig. 6 - Maximum Non-Repetitive Surge Current

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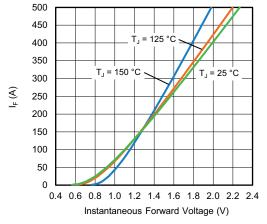
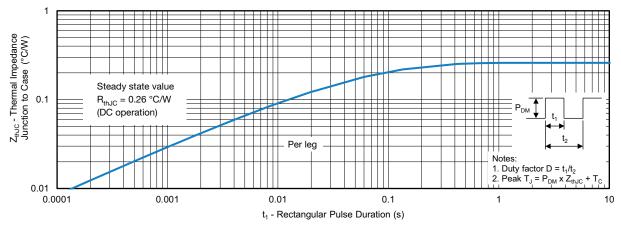


Fig. 7 - Typical Forward Voltage Characteristics





#### **ORDERING INFORMATION TABLE**

Device code	VS-	R	Α	160	F	Α	120		
		2	3	4	5	6	7		
	1 -	1 - Vishay Semiconductors product							
	2 -	Standard recovery diode							
	3 -	Pre	Present silicon generation						
	4 -	Cur	rent rati	ng (160	= 160 A	A)			
	5 -	Circ	cuit conf	iguratior	n (2 sep	arate di	iodes, p		
	6 -	Pac	kage in	dicator (	SOT-22	27 stanc	lard ins		
	7 -	Vol	tage rati	ng (120	= 1200	V)			

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## Vishay Semiconductors

CIRCUIT CONFI	GURATION	
CIRCUIT DESCRIPTION	CIRCUIT CONFIGURATION CODE	CIRCUIT DRAWING
Two separate diodes, parallel pin-out	F	Lead Assignment

LINKS TO RELATED DOCUMENTS						
Dimensions www.vishay.com/doc?95423						
Packaging information	www.vishay.com/doc?95425					

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SOT-227 Generation 2

#### **DIMENSIONS** in millimeters (inches)



#### Note

• Controlling dimension: millimeter



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